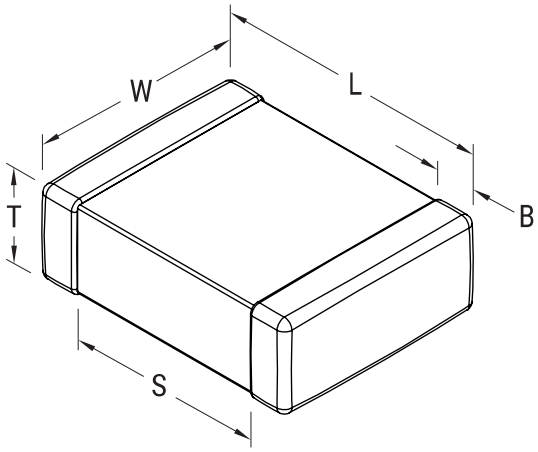
# C1206S111GFGACTU

Aliases (C1206S111GFGAC7800)

SMD Comm C0G HV FE, Ceramic, 110 pF, 2%, 1,500 VDC, C0G, SMD, MLCC, FE-CAP, Floating Electrode, High Voltage, 1206 / 3216




Click here for the 3D model.

| General Information | |
|---|---|
| Series | SMD Comm C0G HV FE |
| Style | SMD Chip |
| Description | SMD, MLCC, FE-CAP, Floating Electrode, High Voltage |
| Features | FE-CAP, Floating Electrode, High Voltage |
| RoHS | Yes |
| Termination | Tin |
| Marking | No |
| Typical Component Weight | 25 mg |
| Shelf Life | 78 Weeks |
| MSL | 1 |

| Dimensions | |
|---|---|
| L | 3.2mm +/-0.2mm |
| W | 1.6mm +/-0.2mm |
| T | 1mm +/-0.10mm |
| S | 1.5mm MIN |
| B | 0.5mm +/-0.25mm |
| Case Code (EIA / mm) | 1206 / 3216 |

| Packaging Specifications | |
|---|---|
| Packaging | T&R, 180mm, Plastic Tape |
| Packaging Quantity | 2500 |

| Specifications | |
|---|---|
| Capacitance | 110 pF |
| Measurement Condition | 1 MHz 1.0Vrms |
| Tolerance | 2% |
| Voltage DC | 1500 VDC |
| Dielectric Withstanding Voltage | 1,800 VDC |
| Temperature Range | -55/+125°C |
| Temp. Coefficient | C0G |
| Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC) | 30 ppm/C, 1MegaHz 1.0Vrms |
| Dissipation Factor | 0.1% 1 MHz 1.0Vrms |
| Aging Rate | 0% Loss/Decade Hour |
| Insulation Resistance | 100 GOhms |

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.



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